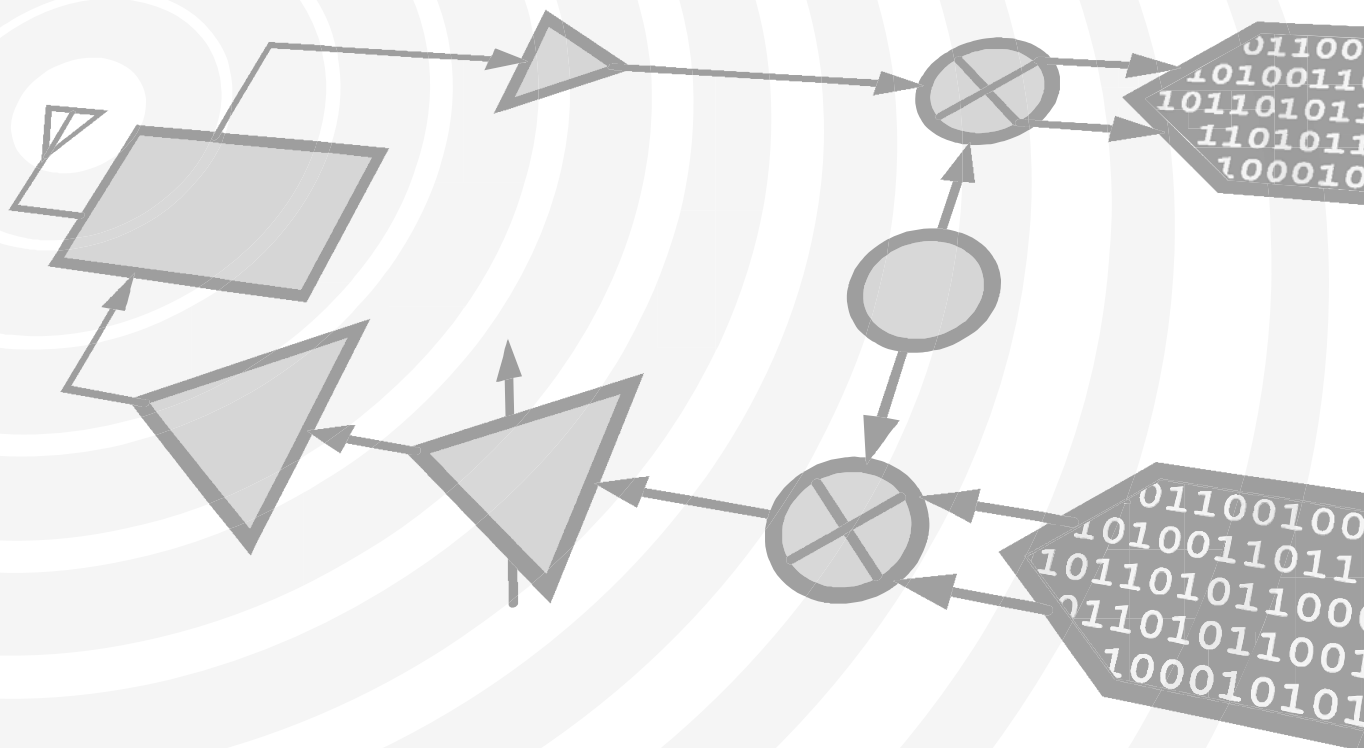




NO CONTENT ON THE ATTACHED DOCUMENT HAS CHANGED



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WIDEBAND LNA MODULE 2 - 20 GHz

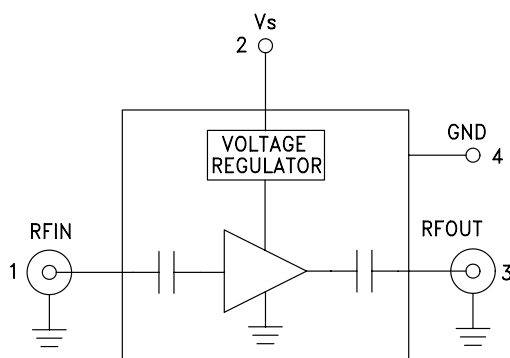


Typical Applications

The HMC-C002 Wideband LNA is ideal for:

- Telecom Infrastructure
- Microwave Radio & VSAT
- Military & Space
- Test Instrumentation
- Fiber Optics

Functional Diagram



Features

Noise Figure: 2 dB @ 8 GHz

Flat Gain: 13 dB $\pm$ 0.5 dB

P1dB Output Power: +18 dBm @ 8 GHz

50 Ohm Matched Input/Output

Regulated Supply and Bias Sequencing

Hermetically Sealed Module

Field Replaceable SMA connectors

-55 °C to +85 °C Operating Temperature

General Description

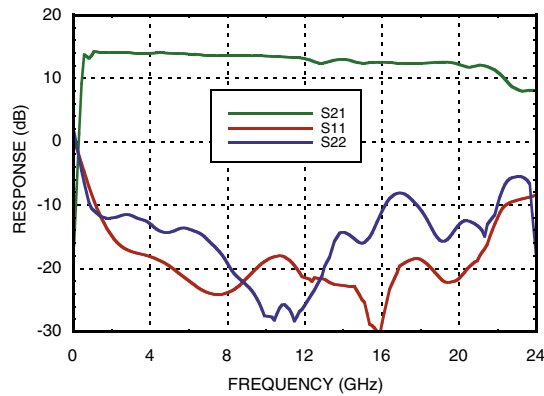
The HMC-C002 is a GaAs MMIC pHEMT Low Noise Distributed Amplifier in a miniature, hermetic module with replaceable SMA connectors which operates between 2 and 20 GHz. The self-biased amplifier provides 13 dB of gain, 2 to 3 dB noise figure and up to +18 dBm of output power at 1 dB gain compression while requiring a single +12V supply. Gain flatness is excellent from 2 - 18 GHz making the HMC-C002 ideal for EW, ECM RADAR and test equipment applications. The wideband amplifier I/Os are internally matched to 50 Ohms and are internally DC blocked.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_s = +11.6\text{V}$ to $+12.4\text{V}$

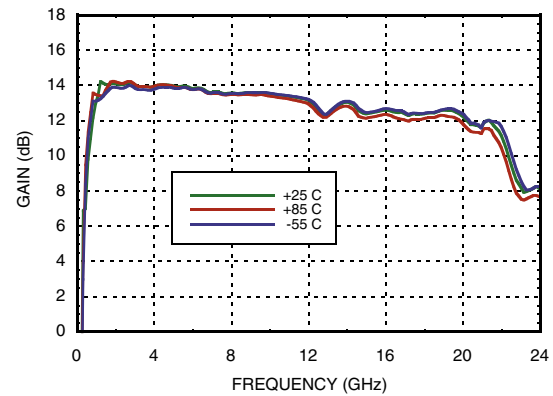
Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range	2.0 - 6.0			6.0 - 12.0			12.0 - 20.0			GHz
Gain	12	14		11	13		10	12		dB
Gain Flatness		± 0.25			± 0.5			± 0.5		dB
Gain Variation Over Temperature		0.008	0.015		0.008	0.015		0.008	0.015	dB/ °C
Noise Figure		2.5	4.5		2.0	3.0		3.0	5.0	dB
Input Return Loss		17			18			18		dB
Output Return Loss		12			15			8		dB
Output Power for 1 dB Compression (P1dB)	15	18		13	16		9	12		dBm
Saturated Output Power (Psat)		21.5			21			19		dBm
Output Third Order Intercept (IP3)		26.5			26			23		dBm
Spurious Response		-50			-60			-60		dBc
Supply Current		93			93			93		mA

**WIDEBAND LNA MODULE
2 - 20 GHz**

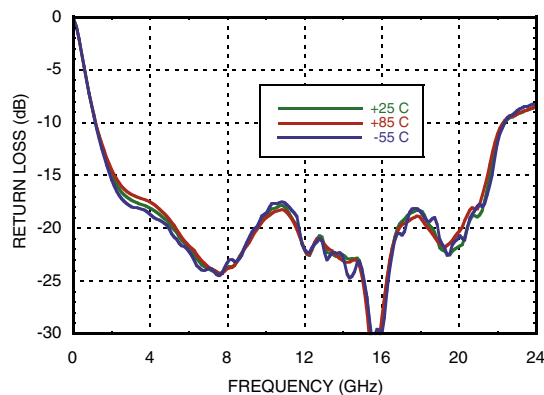
Gain & Return Loss



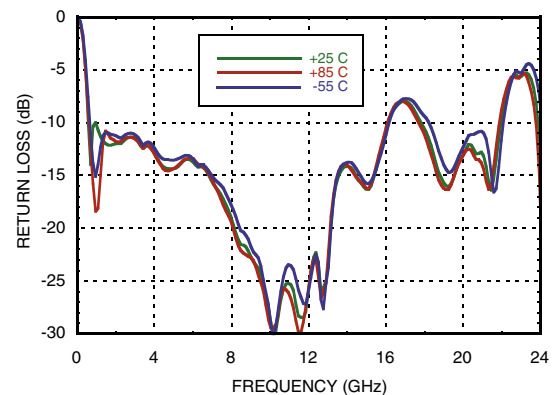
Gain vs. Temperature



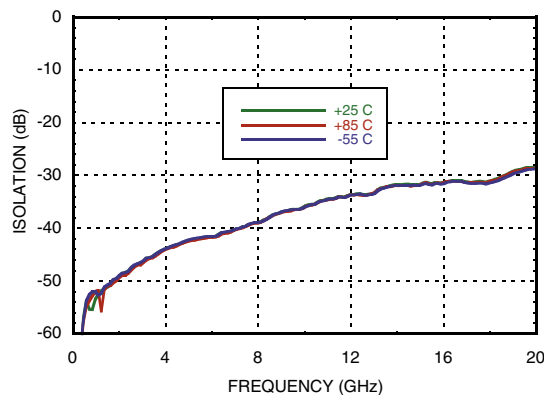
Input Return Loss vs. Temperature



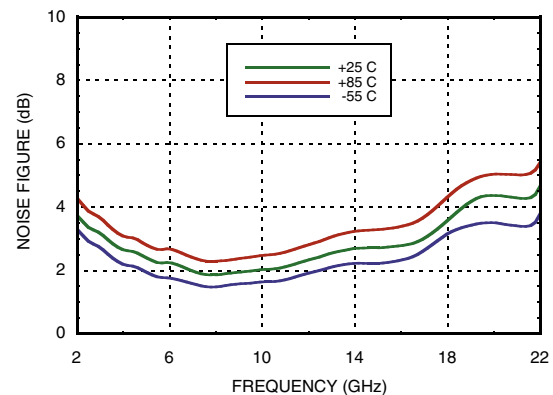
Output Return Loss vs. Temperature



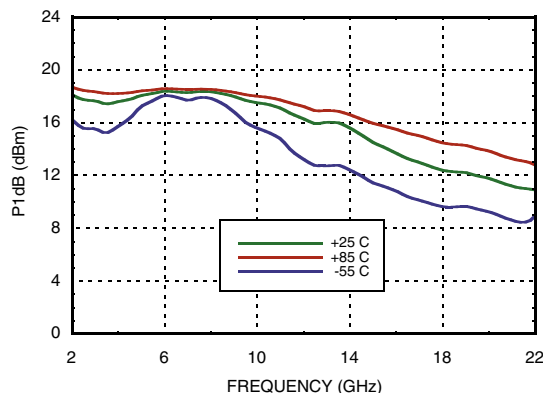
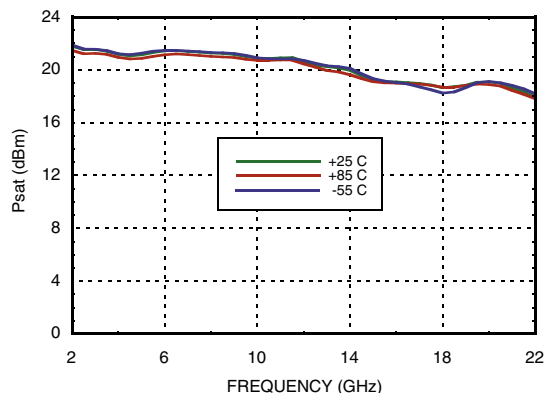
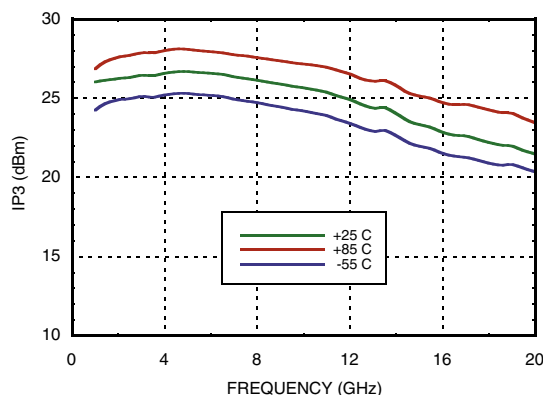
Reverse Isolation vs. Temperature



Noise Figure vs. Temperature



WIDEBAND LNA MODULE 2 - 20 GHz

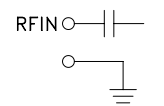
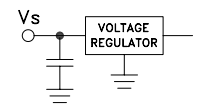
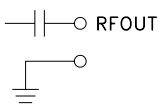
P1dB vs. Temperature

Psat vs. Temperature

Output IP3 vs. Temperature

Absolute Maximum Ratings

Bias Supply Voltage (Vs)	+11 Vdc to +13 Vdc
RF Input Power (RFIN)	+18 dBm
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C



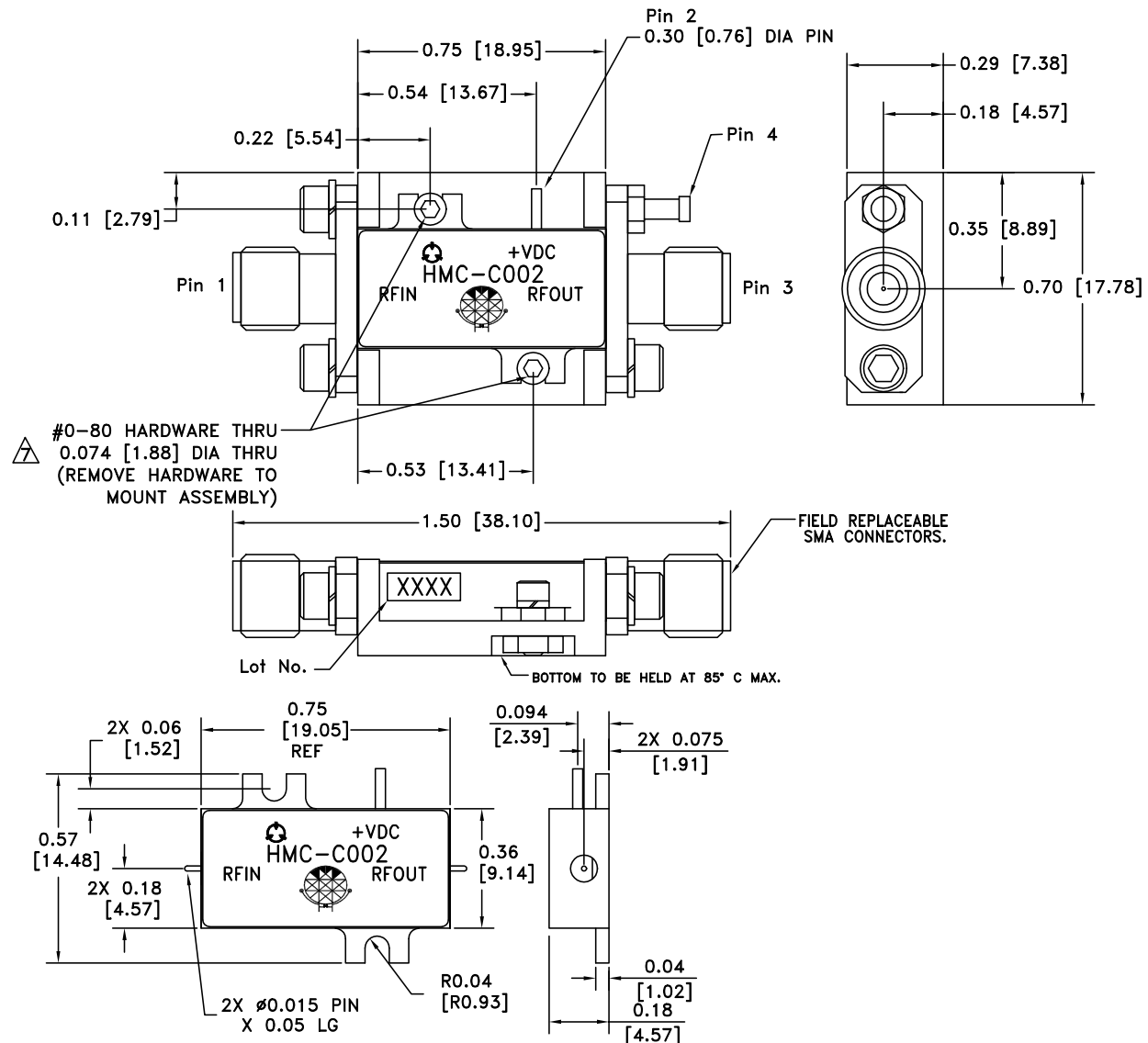
ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	RFIN & RF Ground	RF input connector, SMA female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	
2	Vs	Power supply voltage for the amplifier.	
3	RFOUT & RF Ground	RF output connector, SMA female. This pin is AC coupled and matched to 50 Ohms.	
4	GND	Power supply ground.	

WIDEBAND LNA MODULE 2 - 20 GHz

Outline Drawing



Package Information

Package Type	C-2
Package Weight ^[1]	11.2 gms ^[2]
Spacer Weight	N/A

[1] Includes the connectors

[2] ±1 gms Tolerance

NOTES:

1. PACKAGE, LEADS, COVER MATERIAL: KOVAR™
 2. BRACKET MATERIAL: ALUMINUM
 3. PLATING: ELECTROLYTIC GOLD 50 MICROINCHES MIN., OVER ELECTROLYTIC NICKEL 75 MICROINCHES MIN.
 4. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS].
 5. TOLERANCES ±.005 [0.13] UNLESS OTHERWISE SPECIFIED.
 6. FIELD REPLACEABLE SMA CONNECTORS. TENSOLITE 5602 - 5CCSF OR EQUIVALENT.
- △ TO MOUNT MODULE TO SYSTEM PLATFORM REPLACE 0 - 80 HARDWARE WITH DESIRED MOUNTING SCREWS.

Mouser Electronics

Authorized Distributor

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[HMC-C002](#)